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# T2550H

# Snubberless<sup>™</sup> high temperature 25 A Triacs

### Main features

Symbol	Value	Unit
I <sub>T(RMS)</sub>	25	А
V <sub>DRM</sub> /V <sub>RRM</sub>	600	V
I <sub>GT (Q1)</sub>	50	mA

## Description

Specifically designed for use in high temperature environment (found in hot appliances such as cookers, ovens, hobs, electric heaters, coffee machines...), the new 25 A **T2550H** triacs provide an enhanced performance in terms of power loss and thermal dissipation. This allows for optimization of the heatsinking dimensioning, leading to space and cost effectivness when compared to electro-mechanical solutions.

Based on ST snubberless technology, they offer high commutation switching capabilities and high noise immunity levels. And, thanks to their clip assembly technique, they provide a superior performance in surge current handling.

Table 1.	Abcoluto	maximum	ratings
	ADSUIULE	maximum	raunys

Symbol	Parame	Value	Unit		
I <sub>T(RMS)</sub>	RMS on-state current (full sine wave)		$T_c = 125^{\circ}C$	25	А
	Non repetitive surge peak on-state	F = 50 Hz	t = 20 ms	250	А
I <sub>TSM</sub>	current (full cycle, $T_j$ initial = 25° C)	F = 60 Hz	t = 16.7 ms	260	А
l <sup>2</sup> t	I <sup>2</sup> t Value for fusing	t <sub>p</sub> = 10 ms		340	A <sup>2</sup> s
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$	F = 120 Hz	F = 120 Hz $T_j = 150^{\circ}C$		A/µs
V <sub>DSM</sub> /V <sub>RSM</sub>	Non repetitive surge peak off-state voltage	e peak off-state $t_p = 10 \text{ ms}$ $T_j = 25^{\circ}\text{C}$		700	V
I <sub>GM</sub>	Peak gate current $t_p = 20 \ \mu s$ $T_j = 1$		T <sub>j</sub> = 150°C	4	A
P <sub>G(AV)</sub>	Average gate power dissipation $T_j = 150^{\circ}C$		1	W	
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 150	°C



Order code

Part Number	Marking
T2550H-600TRG	T2550H600T

# 1 Characteristics

### Table 2.Electrical Characteristics ( $T_i = 25^{\circ}C$ , unless otherwise specified)

Symbol	Test Conditions Qua			Value	Unit
I <sub>GT</sub> <sup>(1)</sup>	$V_D = 12 V R_I = 33 \Omega$	1 - 11 - 111	MAX.	50	mA
V <sub>GT</sub>	AD = 15 A D = 20.75	-    -	MAX.	1.3	V
$V_{GD}$	$V_{D} = V_{DRM}  R_{L} = 3.3 \text{ k}\Omega  T_{j} = 150^{\circ} \text{ C} \qquad \text{ I - II - II}$		MIN.	0.15	V
I <sub>H</sub> <sup>(2)</sup>	I <sub>T</sub> = 500 mA		MAX.	75	mA
١L	I <sub>G</sub> = 1.2 I <sub>GT</sub> I - II - III		MAX.	90	mA
dV/dt <sup>(2)</sup>	$V_D = 67\% V_{DRM}$ gate open $T_j = 150^{\circ} C$		MIN.	500	V/µs
(dl/dt)c <sup>(2)</sup>	Without snubber $T_j = 150^{\circ} C$		MIN.	11.1	A/ms

1. minimum  $I_{GT}$  is guaranted at 10% of  $I_{GT}$  max.

2. for both polarities of A2 referenced to A1.

### Table 3.Static Characteristics

Symbol	Test Conditions			Value	Unit
V <sub>T</sub> <sup>(1)</sup>	I <sub>TM</sub> = 35 A t <sub>p</sub> = 380 μs	$T_j = 25^{\circ}C$	MAX.	1.5	V
V <sub>to</sub> <sup>(1)</sup>	Threshold voltage	$T_j = 150^{\circ}C$	MAX.	0.80	V
R <sub>d</sub> <sup>(1)</sup>	Dynamic resistance	T <sub>j</sub> = 150°C	MAX.	19	mΩ
	V -V	$T_j = 25^{\circ}C$		5	μA
I <sub>DRM</sub>	I <sub>DRM</sub> V <sub>DRM</sub> = V <sub>RRM</sub>	$T_j = 150^{\circ}C$	MAX.	8.5	
I <sub>RRM</sub>	V <sub>DRM</sub> /V <sub>RBM</sub> = 400 V (at mains peak voltage)	T <sub>j</sub> = 150°C		5.5	mA

1. for both polarities of A2 referenced to A1.

### Table 4. Thermal resistance

Symbol	Parameter	Value	Unit
R <sub>th(j-c)</sub>	Junction to case (AC)	0.8	°C/W

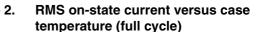


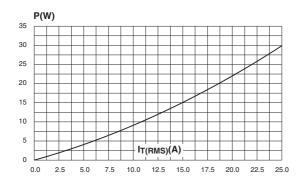
125

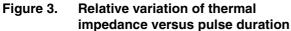
150

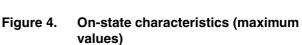
### T2550H

#### Maximum power dissipation versus Figure 2. Figure 1. RMS on-state current (full cycle)







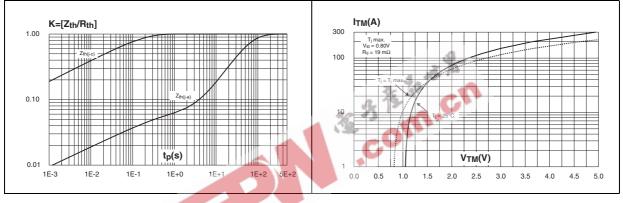


50

T<sub>C</sub>(°C)

75

100



IT(RMS)(A)

25

30

25

20

15

10

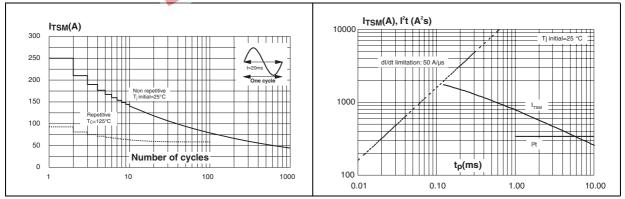
5

0

0

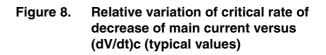
Surge peak on-state current versus Figure 6. Figure 5. number of cycles

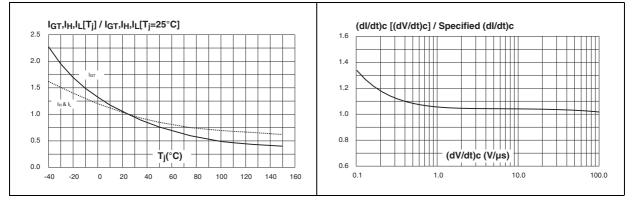
Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10$  ms and corresponding value of  $l^2t$ 



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### Figure 7. Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)



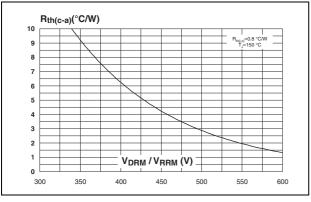


# Figure 9. Relative variation of critical rate of Figure 10. decrease of main current versus junction temperature

 Leakage current versus junction temperature for different values of blocking voltage (typical values)



Figure 11. Acceptable repetitive peak off-state voltage versus case-ambient thermal resistance





# 2 Ordering information scheme

T 25 50 H - 600 T RG
Triac series
Current   25 = 25A
Sensitivity 50 = 50mA
Temperature H = High
Voltage 600 = 600V
Package   T = TO-220AB
Packing mode
A State of the
 RG = Tube



# 3 Package information

	10-220AB L			Dimensions					
			Ref.	Millimeters Inches					
				Min.	Тур.	Max.	Min.	Тур.	Max.
			Α	15.20		15.90	0.598		0.625
			a1		3.75			0.147	
<b>~</b>	B ØI		a2	13.00		14.00	0.511		0.551
7			В	10.00		10.40	0.393		0.409
1		F	b1	0.61		0.88	0.024		0.034
F			b2	1.23		1.32	0.048		0.051
I4 I3	ф.		С	4.40		4.60	0.173		0.181
		c2	c1	0.49		0.70	0.019		0.027
+  2			c2	2.40	A M	2.72	0.094		0.107
	<del>                                     </del>	12	e	2.40		2.70	0.094		0.106
		M ⊂1	Ð	6.20		6.60	0.244		0.259
	e <sup>→ *</sup> b1		ØI	3.75		3.85	0.147		0.151
			14	15.80	16.40	16.80	0.622	0.646	0.661
			L	2.65		2.95	0.104		0.116
			12	1.14		1.70	0.044		0.066
			13	1.14		1.70	0.044		0.066
			М		2.60			0.102	

Table 5. TO-220AB Dimensions

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



# 4 Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
T2550H-600TRG	T2550H600T	TO-220AB	2.3 g	50	Tube

# 5 Revision history

Date	Revision	Changes	
Apr-2002	5A	Last update.	
13-Feb-2006	6	TO-220AB delivery mode changed from bulk to tube. ECOPACK statement added.	
20-Jun-2006	7	Reformatted to current standards. Figures 6 and 11 replaced.	





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